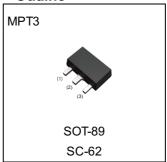


Midium Power Transistors (-30V / -3A)

Parameter	Value
V _{CEO}	-30V
I _C	-3A

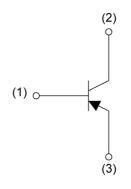
Outline



Features

1)Low saturation voltage, typically V_{CE(sat)} =-0.4V (Max.) (I_C/I_B=-1A/-50mA)
2)High speed switching

•Inner circuit



- (1) Base
- (2) Collector
- (3) Emitter

Application

LOW FREQUENCY AMPLIFIER, HIGH SPEED SWITCHING

Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SAR552P	MPT3	4540	T100	180	12	1000	MF

• Absolute maximum ratings $(T_a = 25^{\circ}C)$

Parameter	Symbol	Values	Unit
Collector-base voltage	V_{CBO}	-30	V
Collector-emitter voltage	V _{CEO}	-30	V
Emitter-base voltage	V_{EBO}	-6	V
Collector current	I _C	-3	Α
Collector current	I _{CP} *1	-6	Α
Dougr dissination	P _D *2	0.5	W
Power dissipation	P _D *3	2.0	W
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	-55 to +150	°C

• Electrical characteristics $(T_a = 25^{\circ}C)$

Dovometer	Cumbal	Canditions	Values			l limit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV _{CBO}	I _C = -100μA	-30	-	-	V
Collector-emitter breakdown voltage	BV _{CEO}	I _C = -1mA	-30	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	I _E = -100μA	6	1	-	V
Collector cut-off current	I _{CBO}	V _{CB} = -30V	ı	1	-1.0	μA
Emitter cut-off current	I _{EBO}	V _{EB} = -4V	ı	1	-1.0	μA
Collector-emitter saturation voltage	V _{CE(sat)} *4	$I_C = -1A$, $I_B = -50 \text{mA}$	-	-200	-400	mV
DC current gain	h _{FE}	$V_{CE} = -2V, I_{C} = -500 \text{mA}$	200	-	500	-
Transition frequency	f _T *4	$V_{CE} = -10V, I_{E} = 100mA,$ f = 100MHz	-	330	-	MHz
Output capacitance	C _{ob}	$V_{CB} = -10V, I_{E} = 0A,$ f = 1MHz	-	25	-	pF
Turn-On time	t _{on}	I _C = -1.5A, I _{B1} = -150mA,	-	35	-	ns
Storage time	t _{stg}	$I_{B2} = 150 \text{mA},$ $V_{CC} \simeq -10 \text{V},$	-	210	-	ns
Fall time	t _f	$R_L = 6.7\Omega$ See test circuit	-	15	-	ns

^{*1} Pw=10ms, Single pulse

^{*2} Each terminal mounted on a reference land.

^{*3} Mounted on a ceramic board.(40×40×0.7mm)

^{*4} Pulsed

● Electrical characteristic curves(T_a = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

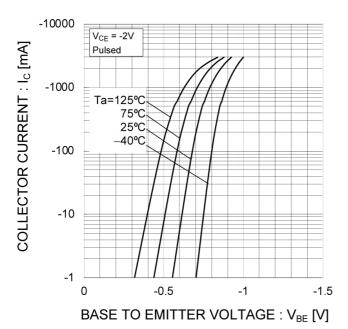
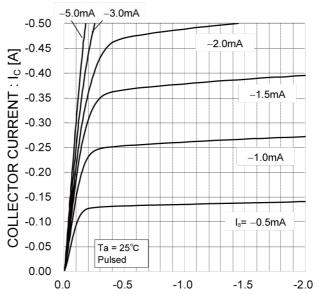


Fig.2 Typical Output Characteristics



COLLECTOR TO EMITTER VOLTAGE: V_{CE} [V]

Fig.3 DC Current Gain vs. Collector Current (I)

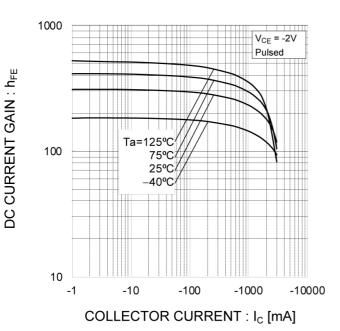
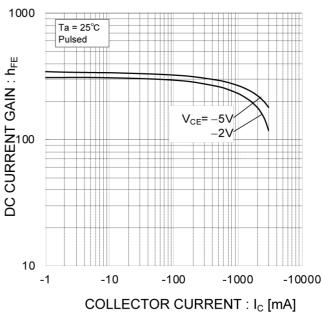


Fig.4 DC Current Gain vs. Collector Current (II)



● Electrical characteristic curves(T_a = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

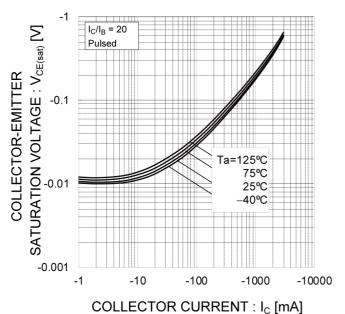


Fig.6 Collector-Emitter Saturation
Voltage vs. Collector Current (II)

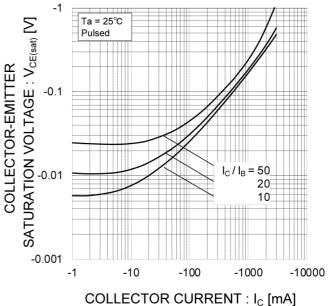


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

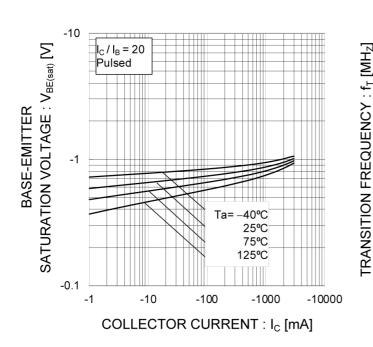
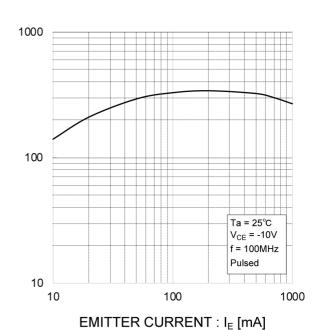


Fig.8 Gain Bandwidth Product vs. Emitter Current



● Electrical characteristic curves(T_a = 25°C)

Fig.9 Emitter Input Capacitance vs.
Emitter-Base Voltage
Collector Output Capacitance vs.
Collector-Base Voltage

-10

Ims

10ms

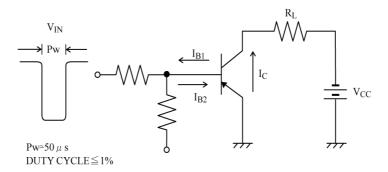
100ms

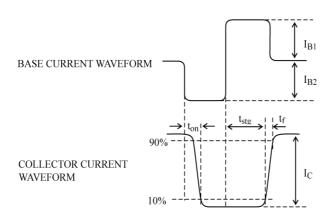
COLLECTOR TO EMITTER VOLTAGE: VCE [V]

Fig.10 Safe Operating Area

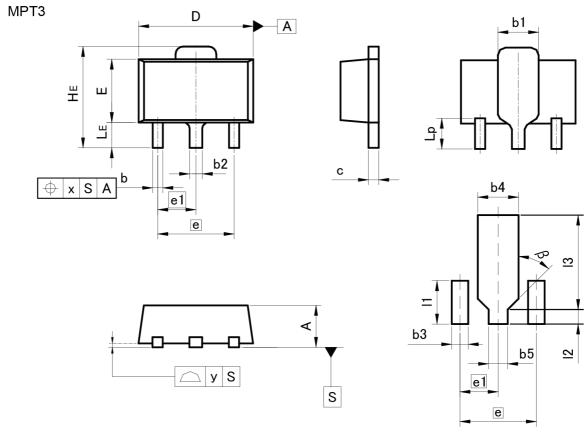
Ta=25°C f=1MHz l=0A lc=0A lc=0

SWITCHING TIME TEST CIRCUIT





Dimensions



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
С	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
E	2.40	2.70	0.094	0.106	
е	3.0	00	0.118		
e1	1.	50	59		
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
х	-	0.15	- 0.006		
У	_	0.10	-	0.004	

DIM	MILIM	ETERS	INCHES		
	MIN	MAX	MIN	MAX	
b3	_	0.65	ı	0.026	
b4	_	1.70	ı	0.067	
b5	_	0.75	-	0.030	
l1	_	1.71	ı	0.067	
12	_	0.58	ı	0.023	
13	_	3.72	-	0.146	
β	45	0	45	0	

Dimension in mm/inches



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